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Applications of **Embedded - Microprocessors**

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details

Product Status	Obsolete
Core Processor	PowerPC e500
Number of Cores/Bus Width	2 Core, 32-Bit
Speed	1.2GHz
Co-Processors/DSP	Signal Processing; SPE, Security; SEC
RAM Controllers	DDR2, DDR3
Graphics Acceleration	No
Display & Interface Controllers	·
Ethernet	10/100/1000Mbps (4)
SATA	·
USB	·
Voltage - I/O	1.5V, 1.8V, 2.5V, 3.3V
Operating Temperature	0°C ~ 105°C (TA)
Security Features	Cryptography, Random Number Generator
Package / Case	1023-BFBGA, FCBGA
Supplier Device Package	1023-FCBGA (33x33)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mpc8572epxatlb

Email: info@E-XFL.COM

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PLL config input setup time with stable SYSCLK before HRESET negation	100	_	μs	
Input setup time for POR configs (other than PLL config) with respect to negation of HRESET	4		SYSCLKs	1
Input hold time for all POR configs (including PLL config) with respect to negation of HRESET	2	_	SYSCLKs	1
Maximum valid-to-high impedance time for actively driven POR configs with respect to negation of HRESET	—	5	SYSCLKs	1

Table 9. RESET Initialization Timing Specifications (continued)

Notes:

2. Reset assertion timing requirements for DDR3 DRAMs may differ.

Table 10 provides the PLL lock times.

Table	10.	PLL	Lock	Times
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Parameter/Condition	Symbol	Min	Typical	Max
PLL lock times	_	100	μs	—
Local bus PLL	_	50	μs	_

6 DDR2 and DDR3 SDRAM Controller

This section describes the DC and AC electrical specifications for the DDR2 and DDR3 SDRAM controller interface of the MPC8572E. Note that the required $GV_{DD}(typ)$ voltage is 1.8Vor 1.5 V when interfacing to DDR2 or DDR3 SDRAM, respectively.

6.1 DDR2 and DDR3 SDRAM Interface DC Electrical Characteristics

Table 11 provides the recommended operating conditions for the DDR SDRAM controller of the MPC8572E when interfacing to DDR2 SDRAM.

Parameter/Condition	Symbol	Min	Мах	Unit	Notes
I/O supply voltage	GV _{DD}	1.71	1.89	V	1
I/O reference voltage	MV _{REF} n	$0.49 imes GV_{DD}$	$0.51 imes GV_{DD}$	V	2
I/O termination voltage	V _{TT}	MV _{REF} <i>n</i> – 0.04	$MV_{REF}n + 0.04$	V	3
Input high voltage	V _{IH}	$MV_{REF}n + 0.125$	GV _{DD} + 0.3	V	_
Input low voltage	V _{IL}	-0.3	MV _{REF} n – 0.125	V	_
Output leakage current	I _{OZ}	-50	50	μA	4
Output high current (V _{OUT} = 1.420 V)	I _{OH}	-13.4	_	mA	—

DDDO ODDAM Late	uface DO Electula	al Okawa ataulatiaa	$f_{a,m} = O(1 - (f_{a,m})) = A = O(1)$,
DURZ SURAW INTE	rtace DU Electric	al Unaracteristics	TOT (= V = (TVD) = T A V	

^{1.} SYSCLK is the primary clock input for the MPC8572E.



Table 14 provides the current draw characteristics for $MV_{REF}n$.

Parameter / Condition		Symbol	Min	Max	Unit	Note
Current draw for MV _{REF} n	DDR2 SDRAM	I _{MVREF} n	—	1500	μA	1
	DDR3 SDRAM			1250		

Table 14. Current Draw Characteristics for MV_{REF} n

1. The voltage regulator for MV_{RFF}n must be able to supply up to 1500 μA or 1250 uA current for DDR2 or DDR3, respectively.

6.2 DDR2 and DDR3 SDRAM Interface AC Electrical Characteristics

This section provides the AC electrical characteristics for the DDR SDRAM controller interface. The DDR controller supports both DDR2 and DDR3 memories. Note that although the minimum data rate for most off-the-shelf DDR3 DIMMs available is 800 MHz, JEDEC specification does allow the DDR3 to run at the data rate as low as 606 MHz. Unless otherwise specified, the AC timing specifications described in this section for DDR3 is applicable for data rate between 606 MHz and 800 MHz, as long as the DC and AC specifications of the DDR3 memory to be used are compliant to both JEDEC specifications as well as the specifications and requirements described in this MPC8572E hardware specifications document.

6.2.1 DDR2 and DDR3 SDRAM Interface Input AC Timing Specifications

Table 15, Table 16, and Table 17 provide the input AC timing specifications for the DDR controller when interfacing to DDR2 and DDR3 SDRAM.

Table 15. DDR2 SDRAM Interface Input AC Timing Specifications for 1.8-V Interface At recommended operating conditions with GV_{DD} of 1.8 V ± 5%

Paramet	er	Symbol	Min	Мах	Unit	Notes
AC input low voltage	>=667 MHz	V _{ILAC}	—	$MV_{REF}n - 0.20$	V	—
	<= 533 MHz		—	MV _{REF} <i>n</i> -0.25		
AC input high voltage	>=667 MHz	V _{IHAC}	$MV_{REF}n + 0.20$	—	V	—
_	<= 533 MHz		$MV_{REF}n + 0.25$	—		

Table 16. DDR3 SDRAM Interface Input AC Timing Specifications for 1.5-V Interface

At recommended operating conditions with GV_{DD} of 1.5 V ± 5%. DDR3 data rate is between 606 MHz and 800 MHz.

Parameter	Symbol	Min	Max	Unit	Notes
AC input low voltage	V _{ILAC}	—	MV _{REF} <i>n</i> – 0.175	V	—
AC input high voltage	V _{IHAC}	$MV_{REF}n + 0.175$	_	V	_



Ethernet Management Interface Electrical Characteristics

Table 42. eTSEC IEEE 1588 AC Timing Specifications (continued)

At recommended operating conditions with LV_{DD}/TV_{DD} of 3.3 V ± 5% or 2.5 V ± 5%

Parameter/Condition	Symbol	Min	Тур	Max	Unit	Note
TSEC_1588_CLK_OUT duty cycle	t _{T1588} CLKOTH /t _{T1588} CLKOUT	30	50	70	%	_
TSEC_1588_PULSE_OUT	t _{T1588OV}	0.5	_	3.0	ns	_
TSEC_1588_TRIG_IN pulse width	t _{T1588} trigh	2*t _{T1588CLK_MAX}	—	_	ns	2

Note:

1.When TMR_CTRL[CKSEL] is set as '00', the external TSEC_1588_CLK input is selected as the 1588 timer reference clock source, with the timing defined in Table 42, "eTSEC IEEE 1588 AC Timing Specifications." The maximum value of t_{T1588CLK} is defined in terms of T_{TX_CLK}, that is the maximum clock cycle period of the equivalent interface speed that the eTSEC1 port is running at. When eTSEC1 is configured to operate in the parallel mode, the T_{TX_CLK} is the maximum clock period of the TSEC1_TX_CLK. When eTSEC1 operates in SGMII mode, the maximum value of t_{T1588CLK} is defined in terms of the recovered clock from SGMII SerDes. For example, for SGMII 10/100/1000 Mbps modes, the maximum value of t_{T1588CLK} is 3600, 360, 72 ns respectively. See the *MPC8572E PowerQUICC™ III Integrated Communications Processor Reference Manual* for detailed description of TMR_CTRL registers.

2. It needs to be at least two times of the clock period of the clock selected by TMR_CTRL[CKSEL].

9 Ethernet Management Interface Electrical Characteristics

The electrical characteristics specified here apply to MII management interface signals ECn_MDIO (management data input/output) and ECn_MDC (management data clock). The electrical characteristics for GMII, SGMII, RGMII, RMII, TBI and RTBI are specified in "Section 8, "Ethernet: Enhanced Three-Speed Ethernet (eTSEC)."

9.1 MII Management DC Electrical Characteristics

The ECn_MDC and ECn_MDIO are defined to operate at a supply voltage of 3.3 V or 2.5 V. The DC electrical characteristics for ECn_MDIO and ECn_MDC are provided in Table 43 and Table 44.

Parameter	Symbol	Min	Max	Unit	Notes
Supply voltage (3.3 V)	LV _{DD} /TV _{DD}	3.13	3.47	V	1, 2
Output high voltage ($LV_{DD}/TV_{DD} = Min, I_{OH} = -1.0 mA$)	V _{OH}	2.10	OV _{DD} + 0.3	V	—
Output low voltage (LV _{DD} /TV _{DD} =Min, I _{OL} = 1.0 mA)	V _{OL}	GND	0.50	V	—
Input high voltage	V _{IH}	2.0	—	V	_
Input low voltage	V _{IL}	—	0.90	V	_
Input high current $(LV_{DD}/TV_{DD} = Max, V_{IN}^{3} = 2.1 \text{ V})$	Iн	_	40	μΑ	—

Table 43. MII Management DC Electrical Characteristics (LV_{DD}/TV_{DD} =3.3 V)



Ethernet Management Interface Electrical Characteristics

Table 43. MII Management DC Electrical Characteristics (LV_{DD}/TV_{DD}=3.3 V) (continued)

Parameter	Symbol	Min	Мах	Unit	Notes
Input low current $(LV_{DD}/TV_{DD} = Max, V_{IN} = 0.5 V)$	Ι _{ΙL}	-600	_	μΑ	_

Note:

1. EC1_MDC and EC1_MDIO operate on LV_{DD}.

2. EC3_MDC & EC3_MDIO and EC5_MDC & EC5_MDIO operate on TV_{DD}.

3. Note that the symbol V_{IN} , in this case, represents the LV_{IN} and TV_{IN} symbol referenced in Table 1.

Table 44. MII Management DC Electrical Characteristics (LV_{DD}/TV_{DD}=2.5 V)

Parameters	Symbol	Min	Мах	Unit	Notes
Supply voltage 2.5 V	LV _{DD/} TV _{DD}	2.37	2.63	V	1,2
Output high voltage $(LV_{DD}/TV_{DD} = Min, IOH = -1.0 mA)$	V _{OH}	2.00	LV _{DD} /TV _{DD} + 0.3	V	_
Output low voltage $(LV_{DD}/TV_{DD} = Min, I_{OL} = 1.0 mA)$	V _{OL}	GND – 0.3	0.40	V	_
Input high voltage	V _{IH}	1.70	$LV_{DD}/TV_{DD} + 0.3$	V	_
Input low voltage	V _{IL}	-0.3	0.70	V	-
Input high current $(V_{IN} = LV_{DD}, V_{IN} = TV_{DD})$	IIH	_	10	μΑ	1, 2,3
Input low current (V _{IN} = GND)	IIL	-15	_	μΑ	3

Note:

 $^1\,$ EC1_MDC and EC1_MDIO operate on LV_DD.

² EC3_MDC & EC3_MDIO and EC5_MDC & EC5_MDIO operate on TV_{DD}.

 $^3\,$ Note that the symbol V_{IN}, in this case, represents the LV_{IN} and TV_{IN} symbols referenced in Table 1.

9.2 MII Management AC Electrical Specifications

Table 45 provides the MII management AC timing specifications. There are three sets of Ethernet management signals (EC1_MDC and EC1_MDIO, EC3_MDC and EC3_MDIO, EC5_MDC and EC5_MDIO). These are not explicitly shown in the table or in the figure following.

Table 45. MII Management AC Timing Specifications

At recommended operating conditions with LV_{DD}/TV_{DD} of 3.3 V ± 5% or 2.5 V ± 5%.

Parameter/Condition	Symbol ¹	Min	Тур	Мах	Unit	Notes
ECn_MDC frequency	f _{MDC}	0.9	2.5	9.3	MHz	2, 3
ECn_MDC period	t _{MDC}	107.5	—	1120	ns	_
ECn_MDC clock pulse width high	t _{MDCH}	32	—	—	ns	_
ECn_MDC to ECn_MDIO delay	t _{MDKHDX}	10	—	16*t _{plb_clk}	ns	5



Table 52. Local Bus General Timing Parameters—PLL Bypassed (continued)

At recommended operating conditions with BV_{DD} of 3.3 V ± 5%

Parameter	Symbol ¹	Min	Мах	Unit	Notes
LGTA/LUPWAIT input hold from local bus clock	t _{LBIXKL2}	-1.3	_	ns	4, 5
LALE output negation to high impedance for LAD/LDP (LATCH hold time)	t _{LBOTOT}	1.5	_	ns	6
Local bus clock to output valid (except LAD/LDP and LALE)	t _{LBKLOV1}	_	-0.3	ns	
Local bus clock to data valid for LAD/LDP	t _{LBKLOV2}	—	-0.1	ns	4
Local bus clock to address valid for LAD	t _{LBKLOV3}	—	0.0	ns	4
Local bus clock to LALE assertion	t _{LBKLOV4}	—	0.0	ns	4
Output hold from local bus clock (except LAD/LDP and LALE)	t _{LBKLOX1}	-3.3	—	ns	4
Output hold from local bus clock for LAD/LDP	t _{LBKLOX2}	-3.3	_	ns	4
Local bus clock to output high Impedance (except LAD/LDP and LALE)	t _{LBKLOZ1}	—	0.2	ns	7
Local bus clock to output high impedance for LAD/LDP	t _{LBKLOZ2}	_	0.2	ns	7

Notes:

- The symbols used for timing specifications herein follow the pattern of t<sub>(First two letters of functional block)(signal)(state) (reference)(state) for inputs and t_{(First two letters of functional block)(reference)(state)(signal)(state)} for outputs. For example, t_{LBIXKH1} symbolizes local bus timing (LB) for the input (I) to go invalid (X) with respect to the time the t_{LBK} clock reference (K) goes high (H), in this case for clock one(1). Also, t_{LBKHOX} symbolizes local bus timing (LB) for the t_{LBK} clock reference (K) to go high (H), with respect to the output (O) going invalid (X) or output hold time.
 </sub>
- 2. All timings are in reference to local bus clock for PLL bypass mode. Timings may be negative with respect to the local bus clock because the actual launch and capture of signals is done with the internal launch/capture clock, which precedes LCLK by t_{LBKHKT}.
- 3. Maximum possible clock skew between a clock LCLK[m] and a relative clock LCLK[n]. Skew measured between complementary signals at BV_{DD}/2.
- 4. All signals are measured from BVDD/2 of the rising edge of local bus clock for PLL bypass mode to 0.4 x BVDD of the signal in question for 3.3-V signaling levels.
- 5. Input timings are measured at the pin.
- t_{LBOTOT} is a measurement of the minimum time between the negation of LALE and any change in LAD. t_{LBOTOT} is programmed with the LBCR[AHD] parameter.
- 7. For purposes of active/float timing measurements, the Hi-Z or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.

NOTE

In PLL bypass mode, LCLK[n] is the inverted version of the internal clock with the delay of t_{LBKHKT} . In this mode, signals are launched at the rising edge of the internal clock and are captured at the falling edge of the internal clock with the exception of LGTA/LUPWAIT (which is captured on the rising edge of the internal clock).



11 Programmable Interrupt Controller

In IRQ edge trigger mode, when an external interrupt signal is asserted (according to the programmed polarity), it must remain asserted for at least 3 system clocks (SYSCLK periods).

12 JTAG

This section describes the AC electrical specifications for the IEEE 1149.1 (JTAG) interface of the MPC8572E.

Table 53 provides the JTAG AC timing specifications as defined in Figure 37 through Figure 39.

Table 53. JTAG	AC Timina	Specifications	(Independent	t of SYSCLK)	1
	/ · · · · · · · · · · · · · · · · · · ·	opeenieanene	(

At recommended operating conditions with OV_{DD} of 3.3 V ± 5%.

Parameter	Symbol ²	Min	Max	Unit	Notes
JTAG external clock frequency of operation	f _{JTG}	0	33.3	MHz	—
JTAG external clock cycle time	t _{JTG}	30	_	ns	—
JTAG external clock pulse width measured at 1.4 V	t _{JTKHKL}	15	—	ns	—
JTAG external clock rise and fall times	t _{JTGR} & t _{JTGF}	0	2	ns	6
TRST assert time	t _{trst}	25	—	ns	3
Input setup times: Boundary-scan data TMS, TDI	t _{JTDVKH} t _{JTIVKH}	4 0		ns	4
Input hold times: Boundary-scan data TMS, TDI	t _{JTDXKH} t _{JTIXKH}	20 25		ns	4
Valid times: Boundary-scan data TDO	t _{jtkldv} t _{jtklov}	4 4	20 25	ns	5
Output hold times: Boundary-scan data TDO	t _{jtkldx} t _{jtklox}	30 30		ns	5



At recommended operating conditions with OV_{DD} of 3.3 V ± 5%. All values refer to V_{IH} (min) and V_{IL} (max) levels (see Table 2).

Parameter	Symbol ¹	Min	Мах	Unit
Capacitive load for each bus line	Cb	—	400	pF

Notes:

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- 1. The symbols used for timing specifications herein follow the pattern t_{(first two letters of functional block)(signal)(state)(reference)(state) for inputs and t_{(first two letters of functional block)(reference)(state)(signal)(state)} for outputs. For example, t_{I2DVKH} symbolizes I²C timing (I2) with respect to the time data input signals (D) reach the valid state (V) relative to the t_{I2C} clock reference (K) going to the high (H) state or setup time. Also, t_{I2SXKL} symbolizes I²C timing (I2) for the time that the data with respect to the t_{I2C} clock reference (K) going to the t_{I2C} clock reference (K) going to the t_{I2C} timing (I2) for the time that the data with respect to the t_{I2C} symbolizes I²C timing (I2) for the time that the data with respect to the t_{I2C} clock reference (K) going to the low (L) state or hold time. Also, t_{I2PVKH} symbolizes I²C timing (I2) for the time that the data with respect to the t_{I2C} clock reference (K) going to the t_{I2C} clock reference (K) going to the t_{I2C} timing (I2) for the time that the data with respect to the t_{I2C} clock reference (K) going to the t_{I2C} clock reference (K) going to the t_{I2C} timing (I2) for the time that the data with respect to the STOP condition (P) reaching the valid state (V) relative to the t_{I2C} clock reference (K) going to the high (H) state or setup time.}
- 2. As a transmitter, the MPC8572E provides a delay time of at least 300 ns for the SDA signal (referred to the VIHmin of the SCL signal) to bridge the undefined region of the falling edge of SCL to avoid unintended generation of START or STOP condition. When the MPC8572E acts as the I2C bus master while transmitting, the MPC8572E drives both SCL and SDA. As long as the load on SCL and SDA are balanced, the MPC8572E would not cause unintended generation of START or STOP condition. Therefore, the 300 ns SDA output delay time is not a concern. If, under some rare condition, the 300 ns SDA output delay time is required for the MPC8572E as transmitter, application note AN2919 referred to in note 4 below is recommended.
- 3. The maximum t_{I2OVKL} has only to be met if the device does not stretch the LOW period (t_{I2CL}) of the SCL signal.
- 4. The requirements for I²C frequency calculation must be followed. Refer to Freescale application note AN2919, *Determining the I²C Frequency Divider Ratio for SCL*.

Figure 40 provides the AC test load for the I^2C .



Figure 40. I²C AC Test Load

Figure 41 shows the AC timing diagram for the I^2C bus.



Figure 41. I²C Bus AC Timing Diagram



High-Speed Serial Interfaces (HSSI)

15 High-Speed Serial Interfaces (HSSI)

The MPC8572E features two Serializer/Deserializer (SerDes) interfaces to be used for high-speed serial interconnect applications. The SerDes1 interface can be used for PCI Express and/or Serial RapidIO data transfers. The SerDes2 is dedicated for SGMII application.

This section describes the common portion of SerDes DC electrical specifications, which is the DC requirement for SerDes Reference Clocks. The SerDes data lane's transmitter and receiver reference circuits are also shown.

15.1 Signal Terms Definition

The SerDes utilizes differential signaling to transfer data across the serial link. This section defines terms used in the description and specification of differential signals.

Figure 43 shows how the signals are defined. For illustration purpose, only one SerDes lane is used for description. The figure shows waveform for either a transmitter output (SDn_TX and SDn_TX) or a receiver input (SDn_RX and $\overline{SDn_RX}$). Each signal swings between A Volts and B Volts where A > B.

Using this waveform, the definitions are as follows. To simplify illustration, the following definitions assume that the SerDes transmitter and receiver operate in a fully symmetrical differential signaling environment.

1. Single-Ended Swing

The transmitter output signals and the receiver input signals SDn_TX, SDn_TX, SDn_RX and SDn_RX each have a peak-to-peak swing of A - B Volts. This is also referred as each signal wire's Single-Ended Swing.

2. Differential Output Voltage, V_{OD} (or Differential Output Swing):

The Differential Output Voltage (or Swing) of the transmitter, V_{OD} , is defined as the difference of the two complimentary output voltages: $V_{SDn_TX} - V_{\overline{SDn_TX}}$. The V_{OD} value can be either positive or negative.

3. Differential Input Voltage, V_{ID} (or Differential Input Swing):

The Differential Input Voltage (or Swing) of the receiver, V_{ID} , is defined as the difference of the two complimentary input voltages: $V_{SDn_RX} - V_{\overline{SDn_RX}}$. The V_{ID} value can be either positive or negative.

4. Differential Peak Voltage, V_{DIFFp}

The peak value of the differential transmitter output signal or the differential receiver input signal is defined as Differential Peak Voltage, $V_{DIFFp} = |A - B|$ Volts.

5. Differential Peak-to-Peak, V_{DIFFp-p}

Because the differential output signal of the transmitter and the differential input signal of the receiver each range from A – B to –(A – B) Volts, the peak-to-peak value of the differential transmitter output signal or the differential receiver input signal is defined as Differential Peak-to-Peak Voltage, $V_{DIFFp-p} = 2*V_{DIFFp} = 2*|(A – B)|$ Volts, which is twice of differential swing in amplitude, or twice of the differential peak. For example, the output differential peak-peak voltage can also be calculated as $V_{TX-DIFFp-p} = 2*|V_{OD}|$.



6. Differential Waveform

- 1. The differential waveform is constructed by subtracting the inverting signal ($\overline{SDn_TX}$, for example) from the non-inverting signal (SDn_TX , for example) within a differential pair. There is only one signal trace curve in a differential waveform. The voltage represented in the differential waveform is not referenced to ground. Refer to Figure 52 as an example for differential waveform.
- 2. Common Mode Voltage, V_{cm}

The Common Mode Voltage is equal to one half of the sum of the voltages between each conductor of a balanced interchange circuit and ground. In this example, for SerDes output, $V_{cm_out} = (V_{SDn_TX} + V_{\overline{SDn_TX}})/2 = (A + B) / 2$, which is the arithmetic mean of the two complimentary output voltages within a differential pair. In a system, the common mode voltage may often differ from one component's output to the other's input. Sometimes, it may be even different between the receiver input and driver output circuits within the same component. It is also referred as the DC offset in some occasion.



Figure 43. Differential Voltage Definitions for Transmitter or Receiver

To illustrate these definitions using real values, consider the case of a CML (Current Mode Logic) transmitter that has a common mode voltage of 2.25 V and each of its outputs, TD and TD, has a swing that goes between 2.5 V and 2.0 V. Using these values, the peak-to-peak voltage swing of each signal (TD or TD) is 500 mV p-p, which is referred as the single-ended swing for each signal. In this example, because the differential signaling environment is fully symmetrical, the transmitter output's differential swing (V_{OD}) has the same amplitude as each signal's single-ended swing. The differential output signal ranges between 500 mV and –500 mV, in other words, V_{OD} is 500 mV in one phase and –500 mV in the other phase. The peak differential voltage (V_{DIFFp}) is 500 mV. The peak-to-peak differential voltage (V_{DIFFp}) is 1000 mV p-p.

15.2 SerDes Reference Clocks

The SerDes reference clock inputs are applied to an internal PLL whose output creates the clock used by the corresponding SerDes lanes. The SerDes reference clocks inputs are SD1_REF_CLK and



High-Speed Serial Interfaces (HSSI)

SD1_REF_CLK for PCI Express and Serial RapidIO, or SD2_REF_CLK and SD2_REF_CLK for the SGMII interface respectively.

The following sections describe the SerDes reference clock requirements and some application information.

15.2.1 SerDes Reference Clock Receiver Characteristics

Figure 44 shows a receiver reference diagram of the SerDes reference clocks. Characteristics are as follows:

- The supply voltage requirements for $XV_{DD SRDS2}$ are specified in Table 1 and Table 2.
- SerDes Reference Clock Receiver Reference Circuit Structure
 - The SDn_REF_CLK and SDn_REF_CLK are internally AC-coupled differential inputs as shown in Figure 44. Each differential clock input (SDn_REF_CLK or SDn_REF_CLK) has on-chip 50-Ω termination to SGND_SRDSn (xcorevss) followed by on-chip AC-coupling.
 - The external reference clock driver must be able to drive this termination.
 - The SerDes reference clock input can be either differential or single-ended. Refer to the Differential Mode and Single-ended Mode description below for further detailed requirements.
- The maximum average current requirement that also determines the common mode voltage range
 - When the SerDes reference clock differential inputs are DC coupled externally with the clock driver chip, the maximum average current allowed for each input pin is 8 mA. In this case, the exact common mode input voltage is not critical as long as it is within the range allowed by the maximum average current of 8 mA (refer to the following bullet for more detail), because the input is AC-coupled on-chip.
 - This current limitation sets the maximum common mode input voltage to be less than 0.4 V (0.4 V/50 = 8 mA) while the minimum common mode input level is 0.1 V above SGND_SRDS*n* (xcorevss). For example, a clock with a 50/50 duty cycle can be produced by a clock driver with output driven by its current source from 0 mA to 16 mA (0-0.8 V), such that each phase of the differential input has a single-ended swing from 0 V to 800 mV with the common mode voltage at 400 mV.
 - If the device driving the SD*n*_REF_CLK and $\overline{\text{SD}n_\text{REF}\text{-}\text{CLK}}$ inputs cannot drive 50 Ω to SGND_SRDS*n* (xcorevss) DC, or it exceeds the maximum input current limitations, then it must be AC-coupled off-chip.
- The input amplitude requirement
 - This requirement is described in detail in the following sections.



15.2.3 Interfacing With Other Differential Signaling Levels

- With on-chip termination to SGND_SRDS*n* (xcorevss), the differential reference clocks inputs are HCSL (High-Speed Current Steering Logic) compatible DC-coupled.
- Many other low voltage differential type outputs like LVDS (Low Voltage Differential Signaling) can be used but may need to be AC-coupled due to the limited common mode input range allowed (100 to 400 mV) for DC-coupled connection.
- LVPECL outputs can produce signal with too large amplitude and may need to be DC-biased at clock driver output first, then followed with series attenuation resistor to reduce the amplitude, additionally to AC-coupling.

NOTE

Figure 48 to Figure 51 below are for conceptual reference only. Due to the fact that clock driver chip's internal structure, output impedance and termination requirements are different between various clock driver chip manufacturers, it is very possible that the clock circuit reference designs provided by clock driver chip vendor are different from what is shown below. They might also vary from one vendor to the other. Therefore, Freescale Semiconductor can neither provide the optimal clock driver reference circuits, nor guarantee the correctness of the following clock driver connection reference circuits. The system designer is recommended to contact the selected clock driver chip vendor for the optimal reference circuits with the MPC8572E SerDes reference clock receiver requirement provided in this document.



Figure 49 shows the SerDes reference clock connection reference circuits for LVDS type clock driver. Because LVDS clock driver's common mode voltage is higher than the MPC8572E SerDes reference clock input's allowed range (100 to 400mV), AC-coupled connection scheme must be used. It assumes the LVDS output driver features $50-\Omega$ termination resistor. It also assumes that the LVDS transmitter establishes its own common mode level without relying on the receiver or other external component.



Figure 49. AC-Coupled Differential Connection with LVDS Clock Driver (Reference Only)

Figure 50 shows the SerDes reference clock connection reference circuits for LVPECL type clock driver. Because LVPECL driver's DC levels (both common mode voltages and output swing) are incompatible with MPC8572E SerDes reference clock input's DC requirement, AC-coupling must be used. Figure 50 assumes that the LVPECL clock driver's output impedance is 50Ω . R1 is used to DC-bias the LVPECL outputs prior to AC-coupling. Its value could be ranged from 140Ω to 240Ω depending on clock driver vendor's requirement. R2 is used together with the SerDes reference clock receiver's $50-\Omega$ termination resistor to attenuate the LVPECL output's differential peak level such that it meets the MPC8572E SerDes reference clock's differential input amplitude requirement (between 200mV and 800mV differential peak). For example, if the LVPECL output's differential peak is 900mV and the desired SerDes reference clock input amplitude is selected as 600mV, the attenuation factor is 0.67, which requires R2 = 25Ω . Consult



High-Speed Serial Interfaces (HSSI)



Figure 53. Single-Ended Measurement Points for Rise and Fall Time Matching

The other detailed AC requirements of the SerDes Reference Clocks is defined by each interface protocol based on application usage. Refer to the following sections for detailed information:

- Section 8.3.2, "AC Requirements for SGMII SD2_REF_CLK and SD2_REF_CLK"
- Section 16.2, "AC Requirements for PCI Express SerDes Reference Clocks"
- Section 17.2, "AC Requirements for Serial RapidIO SD1_REF_CLK and SD1_REF_CLK"

15.2.4.1 Spread Spectrum Clock

SD1_REF_CLK/SD1_REF_CLK are designed to work with a spread spectrum clock (+0 to -0.5% spreading at 30-33 KHz rate is allowed), assuming both ends have same reference clock. For better results, a source without significant unintended modulation should be used.

SD2_REF_CLK/SD2_REF_CLK are not to be used with, and should not be clocked by, a spread spectrum clock source.

15.3 SerDes Transmitter and Receiver Reference Circuits

Figure 54 shows the reference circuits for SerDes data lane's transmitter and receiver.



Figure 54. SerDes Transmitter and Receiver Reference Circuits

The DC and AC specification of SerDes data lanes are defined in each interface protocol section below (PCI Express, Serial Rapid IO or SGMII) in this document based on the application usage:

- Section 8.3, "SGMII Interface Electrical Characteristics"
- Section 16, "PCI Express"







16.4.3 Differential Receiver (RX) Input Specifications

Table 63 defines the specifications for the differential input at all receivers (RXs). The parameters are specified at the component pins.

Symbol	Parameter	Min	Nominal	Max	Units	Comments
UI	Unit Interval	399.88	400	400.12	ps	Each UI is 400 ps ± 300 ppm. UI does not account for Spread Spectrum Clock dictated variations. See Note 1.
V _{RX-DIFFp-p}	Differential Input Peak-to-Peak Voltage	0.175	_	1.200	V	$V_{RX-DIFFp-p} = 2^{*} V_{RX-D+} - V_{RX-D-} $ See Note 2.
T _{RX-EYE}	Minimum Receiver Eye Width	0.4			UI	The maximum interconnect media and Transmitter jitter that can be tolerated by the Receiver can be derived as $T_{RX-MAX-JITTER} = 1 - T_{RX-EYE} = 0.6$ UI. See Notes 2 and 3.

Table 63. Differential Receiver (RX) Input Specifications



16.5.1 Compliance Test and Measurement Load

The AC timing and voltage parameters must be verified at the measurement point, as specified within 0.2 inches of the package pins, into a test/measurement load shown in Figure 57.

NOTE

The allowance of the measurement point to be within 0.2 inches of the package pins is meant to acknowledge that package/board routing may benefit from D+ and D- not being exactly matched in length at the package pin boundary.



Figure 57. Compliance Test/Measurement Load

17 Serial RapidIO

This section describes the DC and AC electrical specifications for the RapidIO interface of the MPC8572E for the LP-Serial physical layer. The electrical specifications cover both single and multiple-lane links. Two transmitters (short run and long run) and a single receiver are specified for each of three baud rates, 1.25, 2.50, and 3.125 GBaud.

Two transmitter specifications allow for solutions ranging from simple board-to-board interconnect to driving two connectors across a backplane. A single receiver specification is given that accepts signals from both the short run and long run transmitter specifications.

The short run transmitter should be used mainly for chip-to-chip connections on either the same printed circuit board or across a single connector. This covers the case where connections are made to a mezzanine (daughter) card. The minimum swings of the short run specification reduce the overall power used by the transceivers.

The long run transmitter specifications use larger voltage swings that are capable of driving signals across backplanes. This allows a user to drive signals across two connectors and a backplane. The specifications allow a distance of at least 50 cm at all baud rates.

All unit intervals are specified with a tolerance of +/-100 ppm. The worst case frequency difference between any transmit and receive clock is 200 ppm.

To ensure interoperability between drivers and receivers of different vendors and technologies, AC coupling at the receiver input must be used.



18.2 Mechanical Dimensions of the MPC8572E FC-PBGA

Figure 61 shows the mechanical dimensions of the MPC8572E FC-PBGA package with full lid.



Figure 61. Mechanical Dimensions of the MPC8572E FC-PBGA with Full Lid

NOTES:

- 1. All dimensions are in millimeters.
- 2. Dimensions and tolerances per ASME Y14.5M-1994.
- 3. All dimensions are symmetric across the package center lines unless dimensioned otherwise.
- 4. Maximum solder ball diameter measured parallel to datum A.



Package Description

Table 76. MPC8572E Pinout Listing (continued)

Signal	Signal Name	Package Pin Number	Pin Type	Power Supply	Notes				
IRQ_OUT	Interrupt Output	U24	0	OV _{DD}	2, 4				
1588									
TSEC_1588_CLK	Clock In	AM22	I	LV _{DD}	—				
TSEC_1588_TRIG_IN	Trigger In	AM23	I	LV _{DD}	—				
TSEC_1588_TRIG_OUT	Trigger Out	AA23	0	LV _{DD}	5, 9				
TSEC_1588_CLK_OUT	Clock Out	AC23	0	LV _{DD}	5, 9				
TSEC_1588_PULSE_OUT1	Pulse Out1	AA22	0	LV _{DD}	5, 9				
TSEC_1588_PULSE_OUT2	Pulse Out2	AB23	0	LV _{DD}	5, 9				
	Ethernet Managem	ent Interface 1							
EC1_MDC	Management Data Clock	AL30	0	LV _{DD}	5, 9				
EC1_MDIO	Management Data In/Out	AM25	I/O	LV _{DD}	_				
Ethernet Management Interface 3									
EC3_MDC	Management Data Clock	AF19	0	TV _{DD}	5, 9				
EC3_MDIO	Management Data In/Out	AF18	I/O	TV _{DD}					
	Ethernet Managem	ent Interface 5							
EC5_MDC	Management Data Clock	AF14	0	TV _{DD}	21				
EC5_MDIO	Management Data In/Out	AF15	I/O	TV _{DD}	—				
	Gigabit Ethernet Ro	eference Clock							
EC_GTX_CLK125	Reference Clock	AM24	I	LV _{DD}	32				
	Three-Speed Ethern	net Controller 1							
TSEC1_RXD[7:0]/FIFO1_RXD[7:0]	Receive Data	AM28, AL28, AM26, AK23, AM27, AK26, AL29, AM30	I	LV _{DD}	1				
TSEC1_TXD[7:0]/FIFO1_TXD[7:0]	Transmit Data	AC20, AD20, AE22, AB22, AC22, AD21, AB21, AE21	0	LV _{DD}	1, 5, 9				
TSEC1_COL/FIFO1_TX_FC	Collision Detect/Flow Control	AJ23	I	LV _{DD}	1				
TSEC1_CRS/FIFO1_RX_FC	Carrier Sense/Flow Control	AM31	I/O	LV _{DD}	1, 16				
TSEC1_GTX_CLK	Transmit Clock Out	AK27	0	LV _{DD}					
TSEC1_RX_CLK/FIFO1_RX_C LK	Receive Clock	AL25	I	LV _{DD}	1				



Table 76	MPC8572E	Pinout I	istina ((continued)	`
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Signal	Signal Name	Package Pin Number	Pin Type	Power Supply	Notes
SD1_RX[7:0]	Receive Data (positive)	P32, N30, M32, L30, G30, F32, E30, D32	I	XV _{DD_SR} DS1	_
SD1_RX[7:0]	Receive Data (negative)	P31, N29, M31, L29, G29, F31, E29, D31	I	XV _{DD_SR} DS1	_
SD1_TX[7]	PCIe1 Tx Data Lane 7 / SRIO or PCIe2 Tx Data Lane 3 / PCIe3 TX Data Lane 1	M26	0	XV _{DD_SR} DS1	_
SD1_TX[6]	PCIe1 Tx Data Lane 6 / SRIO or PCIe2 Tx Data Lane 2 / PCIe3 TX Data Lane 0	L24	0	XV _{DD_SR} DS1	_
SD1_TX[5]	PCIe1 Tx Data Lane 5 / SRIO or PCIe2 Tx Data Lane 1	K26	0	XV _{DD_SR} DS1	—
SD1_TX[4]	PCIe1 Tx Data Lane 4 / SRIO or PCIe2 Tx Data Lane 0	J24	0	XV _{DD_SR} DS1	_
SD1_TX[3]	PCIe1 Tx Data Lane 3	G24	0	XV _{DD_SR} DS1	_
SD1_TX[2]	PCIe1 Tx Data Lane 2	F26	0	XV _{DD_SR} DS1	—
SD1_TX[1]	PCIe1 Tx Data Lane 1]	E24	0	XV _{DD_SR} DS1	—
SD1_TX[0]	PCIe1 Tx Data Lane 0	D26	0	XV _{DD_SR} DS1	_
SD1_TX[7:0]	Transmit Data (negative)	M27, L25, K27, J25, G25, F27, E25, D27	0	XV _{DD_SR} DS1	—
SD1_PLL_TPD	PLL Test Point Digital	J32	0	XV _{DD_SR} DS1	17
SD1_REF_CLK	PLL Reference Clock	H32	I	XV _{DD_SR} DS1	_
SD1_REF_CLK	PLL Reference Clock Complement	H31	I	XV _{DD_SR} DS1	—
Reserved	—	C29, K32	_	—	26
Reserved	—	C30, K31		—	27
Reserved	—	C24, C25, H26, H27	_	—	28
Reserved	_	AL20, AL21		—	29
	SerDes (x4)	SGMII			
SD2_RX[3:0]	Receive Data (positive)	AK32, AJ30, AF30, AE32	Ι	XV _{DD_SR} DS2	—



21 System Design Information

This section provides electrical and thermal design recommendations for successful application of the MPC8572E.

21.1 System Clocking

The platform PLL generates the platform clock from the externally supplied SYSCLK input. The frequency ratio between the platform and SYSCLK is selected using the platform PLL ratio configuration bits as described in Section 19.2, "CCB/SYSCLK PLL Ratio." The MPC8572E includes seven PLLs, with the following functions:

- Two core PLLs have ratios that are individually configurable. Each e500 core PLL generates the core clock as a slave to the platform clock. The frequency ratio between the e500 core clock and the platform clock is selected using the e500 PLL ratio configuration bits as described in Section 19.3, "e500 Core PLL Ratio."
- The DDR complex PLL generates the clocking for the DDR controllers.
- The local bus PLL generates the clock for the local bus.
- The PLL for the SerDes1 module is used for PCI Express and Serial Rapid IO interfaces.
- The PLL for the SerDes2 module is used for the SGMII interface.

21.2 Power Supply Design

21.2.1 PLL Power Supply Filtering

Each of the PLLs listed above is provided with power through independent power supply pins $(AV_{DD}PLAT, AV_{DD}CORE0, AV_{DD}CORE1, AV_{DD}DDR, AV_{DD}LBIU, AV_{DD}SRDS1 and AV_{DD}SRDS2 respectively).$ The AV_{DD} level should always be equivalent to V_{DD}, and preferably these voltages are derived directly from V_{DD} through a low frequency filter scheme such as the following.

There are a number of ways to reliably provide power to the PLLs, but the recommended solution is to provide independent filter circuits per PLL power supply as illustrated in Figure 62, one to each of the AV_{DD} pins. By providing independent filters to each PLL the opportunity to cause noise injection from one PLL to the other is reduced.

This circuit is intended to filter noise in the PLLs resonant frequency range from a 500 kHz to 10 MHz range. It should be built with surface mount capacitors with minimum Effective Series Inductance (ESL). Consistent with the recommendations of Dr. Howard Johnson in *High Speed Digital Design: A Handbook of Black Magic* (Prentice Hall, 1993), multiple small capacitors of equal value are recommended over a single large value capacitor.

Each circuit should be placed as close as possible to the specific AV_{DD} pin being supplied to minimize noise coupled from nearby circuits. It should be possible to route directly from the capacitors to the AV_{DD} pin, which is on the periphery of the 1023 FC-PBGA footprint, without the inductance of vias.



Table 85 summarizes the signal impedance targets. The driver impedances are targeted at minimum V_{DD} , nominal OV_{DD} , 105°C.

Impedance	Local Bus, Ethernet, DUART, Control, Configuration, Power Management	DDR DRAM	Symbol	Unit
R _N	45 Target	18 Target (full strength mode) 36 Target (half strength mode)	Z ₀	Ω
R _P	45 Target	18 Target (full strength mode) 36 Target (half strength mode)	Z ₀	Ω

Table 85. Impedance Characteristics

Note: Nominal supply voltages. See Table 1, $T_i = 105^{\circ}C$.

21.8 Configuration Pin Muxing

The MPC8572E provides the user with power-on configuration options which can be set through the use of external pull-up or pull-down resistors of 4.7 k Ω on certain output pins (see customer visible configuration pins). These pins are generally used as output only pins in normal operation.

While $\overline{\text{HRESET}}$ is asserted however, these pins are treated as inputs. The value presented on these pins while $\overline{\text{HRESET}}$ is asserted, is latched when $\overline{\text{HRESET}}$ deasserts, at which time the input receiver is disabled and the I/O circuit takes on its normal function. Most of these sampled configuration pins are equipped with an on-chip gated resistor of approximately 20 kΩ. This value should permit the 4.7-kΩ resistor to pull the configuration pin to a valid logic low level. The pull-up resistor is enabled only during $\overline{\text{HRESET}}$ (and for platform /system clocks after $\overline{\text{HRESET}}$ deassertion to ensure capture of the reset value). When the input receiver is disabled the pull-up is also, thus allowing functional operation of the pin as an output with minimal signal quality or delay disruption. The default value for all configuration bits treated this way has been encoded such that a high voltage level puts the device into the default state and external resistors are needed only when non-default settings are required by the user.

Careful board layout with stubless connections to these pull-down resistors coupled with the large value of the pull-down resistor should minimize the disruption of signal quality or speed for output pins thus configured.

The platform PLL ratio, DDR complex PLL and e500 PLL ratio configuration pins are not equipped with these default pull-up devices.

21.9 JTAG Configuration Signals

Correct operation of the JTAG interface requires configuration of a group of system control pins as demonstrated in Figure 66. Care must be taken to ensure that these pins are maintained at a valid deasserted state under normal operating conditions as most have asynchronous behavior and spurious assertion gives unpredictable results.

Boundary-scan testing is enabled through the JTAG interface signals. The $\overline{\text{TRST}}$ signal is optional in the IEEE Std 1149.1 specification, but it is provided on all processors built on Power Architecture technology. The device requires $\overline{\text{TRST}}$ to be asserted during power-on reset flow to ensure that the JTAG boundary